

1.Description

This device has been specifically designed to protect sensitive components which are connected to high-speed data and transmission lines from overvoltage caused by ESD (electrostatic discharge), CDE (Cable Discharge Events), and lightning.

3.Applications

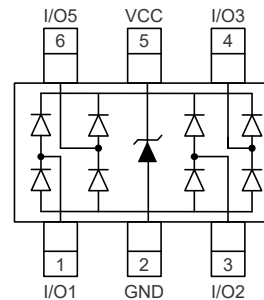
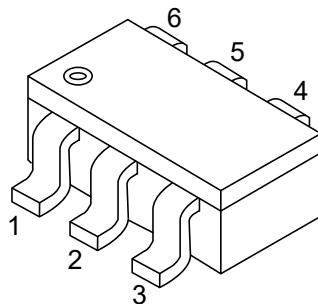
- Digital Visual Interface (DVI)
- USB 1.1/2.0/OTG
- IEEE 1394 Firewire Ports
- Notebooks & Handhelds

2.Features

- Protects four I/O lines and one Vcc line
- Low capacitance
- Working voltages : 5V
- Low leakage current
- Low capacitance for high-speed interfaces
- No insertion loss to 2.0GHz
- Response Time is < 1 ns

- Projection TV & Monitors
- Set-top box
- Flat Panel Displays
- PCI Express

4.Pinning information



SOT23-6



5. Absolute Maximum Ratings $T_A = 25^\circ\text{C}$

Parameter	Symbol	Maximum	Units
Peak Pulse Power (8/20 μs)	P_{pp}	150	W
Peak Pulse Current (8/20 μs)	I_{pp}	5	A
ESD per IEC 61000-4-2 (Air)	V_{ESD}	± 15	kV
ESD per IEC 61000-4-2 (Contact)		± 8	kV
Junction Temperature Range	T_{OPT}	-55 to 150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 to 150	$^\circ\text{C}$



6. Electrical Characteristic ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Reverse Working Voltage	V_{RWM}	Any I/O pin to GND			5	V
Breakdown Voltage	V_{BR}	$I_T=1\text{mA}$, Any I/O pin to GND	6			V
Reverse leakage current	I_R	$V_{RWM}=5\text{V}$, Any I/O pin to GND			1	μA
Diode Forward Voltage	V_F	$I_F=15\text{mA}$			1.2	V
Clamping Voltage 1	V_{C1}	$I_{PP}=1\text{A}$, $t_P=8/20\mu\text{s}$ any I/O pin to GND			15	V
Clamping Voltage 2	V_{C2}	$I_{PP}=5\text{A}$, $t_P=8/20\mu\text{s}$ any I/O pin to GND			28	V
Junction Capacitance 1	C_{J1}	$V_R=0\text{V}$, $f=1\text{MHz}$ Between I/O pins			0.4	pF
Junction Capacitance 2	C_{J2}	$V_R=0\text{V}$, $f=1\text{MHz}$ Any I/O pin to GND			0.8	pF

Notes: I/O pins are pin 1,3,4,6.

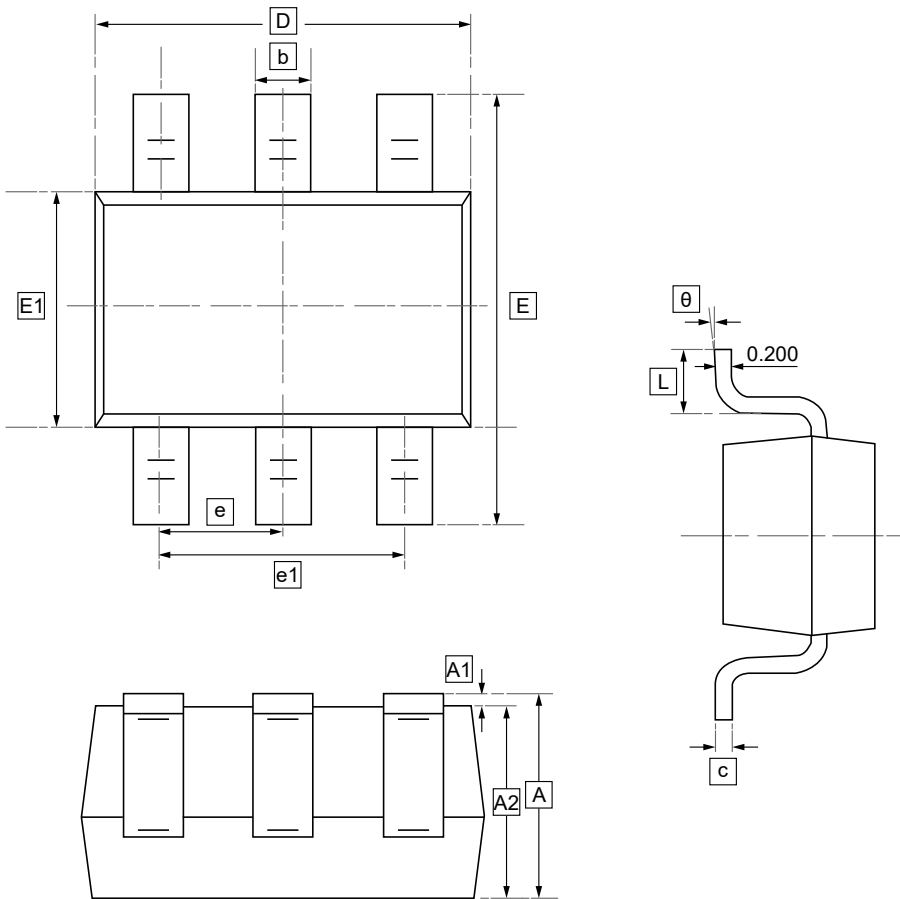


7. Typical characteristic

Figure 1: Pulse Waveform	Figure 2: Non-Repetitive Peak Pulse Power vs. Pulse Time
Figure 3: Power Derating Curve	Figure 4: Junction Capacitance vs. Reverse Voltage



8.SOT-23-6 Package Outline Dimensions

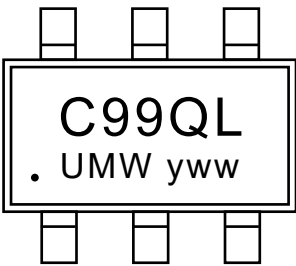


DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	b	c	D	E1	E	e	e1	L	θ
Min	1.050	0.000	1.050	0.300	0.100	2.820	1.500	2.650	0.950	1.800	0.300	0°
Max	1.250	0.100	1.150	0.500	0.200	3.020	1.700	2.950	BSC	2.000	0.600	8°



9.Ordering information



y: Year Code
ww: Week Code

Order Code	Package	Base QTY	Delivery Mode
UMW AZC099-04S	SOT23-6	3000	Tape and reel



10.Disclaimer

UMW reserves the right to make changes to all products, specifications. Customers should obtain the latest version of product documentation and verify the completeness and currency of the information before placing an order.

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